

Reconfigurable Infrared Ellipse-Shape Metamaterial

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Abstract—The designs of cross ellipse-shape metamaterial (ESM) in infrared (IR) wavelength range are presented. They are composed of a tailored gold (Au) layer on silicon (Si) substrate. The characterizations of proposed devices can be manipulated their electromagnetic responses between single-band and dual-band resonances by changing different ratio of macro-axis and minor-axis of ESM. The electromagnetic behavior of dual-band resonance exhibits the resonance with broad bandwidth or narrow bandwidth, while the corresponding free spectral range (FSR) could be controlled from 0.154 μm to 0.607 μm depending on the design of symmetrical or asymmetrical ESM. According to these optical characteristics of cross ESM, we can design ESM-like nanostructures to realize IR filter, polarization switch, band switch, and high-efficiency sensor applications.

Keywords—metamaterial, infrared filter, resonator

I. INTRODUCTION

Metamaterials have unique electromagnetic characteristics that are unable to be found in natural materials and have great research values [1-3], such as negative refraction index and invisible cloaking [4-6]. In view of these merits of metamaterials, there have been reported many literatures to demonstrate metamaterials used in widespread applications, such as sensor, switch, filter, etc. By properly tailoring the geometrical dimension of metamaterial, the electromagnetic behaviors can be manipulated, e.g. amplitude, wavelength, phase, and polarization [2-7].

In this study, we propose a series of designs of cross ellipse-shape metamaterial (ESM) with different ratio of the minor-axis and the macro-axis of each design in infrared (IR) spectrum range. The designs of cross ESM are composed of a textured Au layer on Si substrate, which shows switch function of single-band to dual-band resonances, and tunable free spectral range (FSR). These characteristics can be contributed to the arrangement of minor-axis and the macro-axis of ESM. The proposed ESM are simple structures, easy to manufacture, and low cost. Such strategy provides the great potential uses for next generation IR opto-electronic devices.

II. MATERIALS AND METHODS

The composition of proposed device is a tailored 200-nm-thick Au layer with cross ellipse-shape on Si substrate. We define the ratio of minor-axis (b) and the macro-axis (a) of ESM as $r = b/a$. For the discussion of the influence of r value, a value is kept as constant while b value is variable. The period of cross ESM is kept as constant as $P_x = P_y = 3 \mu\text{m}$. The schematic drawing of proposed device is indicated in the inserted image of Fig. 1(a). When changing the ratio ($r = b_1/a_1 = b_2/a_2$), two ESMs are varied simultaneously. It means the electromagnetic behaviors are identical at TE and TM modes. The relationships of resonance and r value of cross ESM are summarized in Fig. 1(a). Fig. 1(b) shows the corresponding E-field and H-field distributions of $r = 0.2, 0.5, 0.8$, and 1.0,

respectively. It can be seen that E-field and H-field energies are focused on two sides of the lateral ESM.

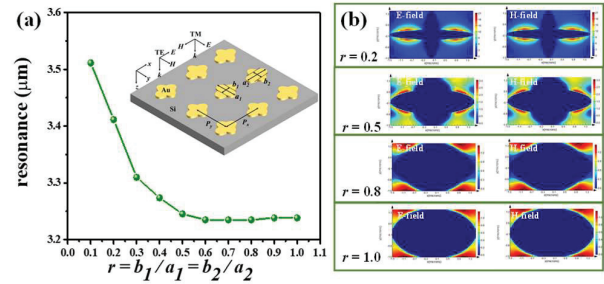


Fig. 1. (a) The relationship of resonance and r value. Inserted schematic drawing is the proposed cross ESM device. (b) The E-field and H-field distributions of cross ESM with $r = 0.2, 0.5, 0.8$, and 1.0, respectively.

III. RESULTS AND DISCUSSIONS

To figure out the influence of changing r_2 with different r_1 value, the r_1 value is kept as constant as 0.1 and r_2 is varied from 0.1 to 1.0 as shown in Fig. 2. Fig. 2(a) and (b) show the transmission spectra of cross ESM with different r_2 . The electromagnetic response is single-band and polarization-independent with a resonance dip (ω_0) at 3.104 μm for r_2 varied from 1.0 to 0.9 at TE and TM modes. When r_2 is 0.8, the resonance becomes polarization-dependent that has two resonances ($\omega_1 = 3.005 \mu\text{m}$ and $\omega_2 = 3.238 \mu\text{m}$) at TE mode, and ($\omega_1 = 3.011 \mu\text{m}$ and $\omega_2 = 3.299 \mu\text{m}$) at TM mode. At TE mode, the electromagnetic response is nearly identical for r_2 is 0.7 and 0.6. When r_2 is varied from 0.5 to 0.2, resonance dip (ω_0) is vanished and there are two resonant peaks (ω_1 and ω_2) varied from 3.002 μm to 3.029 μm and from 3.193 μm to 3.373 μm for ω_1 and ω_2 , respectively. The corresponding tuning ranges are 27 nm and 180 nm. At TM mode, there are two resonant peaks for r_2 varying from 0.8 to 0.2. The tuning range of ω_1 is 30 nm from 3.011 μm to 3.041 μm and that of ω_2 is 349 nm from 3.299 μm to 3.648 μm . The tuning ranges of FSR are 135 nm from 0.368 to 0.233 μm and from 0.288 to 0.607 μm for TE and TM modes.

Fig. 3(a) shows the relationship of resonance and r_2 of cross ESM kept r_1 as constant as 0.1. The electromagnetic response of cross ESM with different r_2 exhibits hysteresis behavior at TE and TM modes. To better understand the electromagnetic behaviors of varying r_2 under the different r_1 value, the relationships of resonance peak (ω_2) and r_2 of cross ESM under the conditions of $r_1 = 0.3$ and $r_1 = 0.5$ are shown in Fig. 3(b) and (c), respectively. The results exhibit the hysteresis behavior at TE and TM modes, which are identical to those in Fig. 3(a). The TM response is overall blue-shifted by increasing r_1 value and then saturated and kept stable at 3.23 μm . While the trend of TE response is approximately unchanged by increasing r_1 value. This can be explained by keeping a_2 as constant and changing b_2 to define different r_2

along y-direction of ESM. The electromagnetic characteristics of cross ESM at TE mode mainly depends on the horizontal ESM while those of cross ESM at TM mode mainly depends on the vertical ESM. Fig. 3(d) shows the E-field and H-field distributions of $r_2 = 0.2, 0.5, 0.8$, and 1.0 , respectively under the condition of $r_1 = 0.1$. The E-field energy is focused on top and bottom sides of horizontal ESM (along x-direction) while the H-field energy is focused on top and bottom sides of vertical ESM (along y-direction). It is clearly explained the characteristics of electromagnetic response at TE mode mainly depends on the horizontal ESM while that at TM mode mainly depends on the vertical ESM.

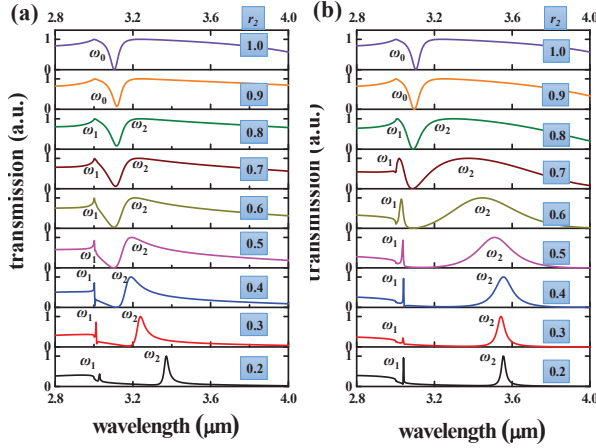


Fig. 2. Transmission spectra of cross ESM with different r_2 value at (a) TE mode and (b) TM mode. The r_1 is kept as constant as 0.1.

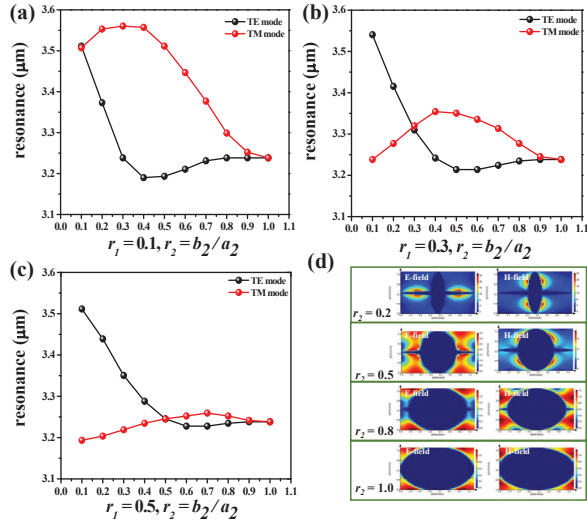


Fig. 3. The relationships of resonance and r_2 value for cross ESM under the conditions of (a) $r_1 = 0.1$, (b) $r_1 = 0.3$, and (c) $r_1 = 0.5$. (d) The E-field and H-field distributions of cross ESM with $r_2 = 0.2, 0.5, 0.8$, and 1.0 , respectively under the condition of $r_1 = 0.1$.

Fig. 4(a) shows the schematic drawing of dual-layer ESM. This dual-layer ESM is designed with a gap between top and bottom ESM (h). The electromagnetic responses of dual-layer ESM can be tuned by changing h value using MEMS technique. The r_1 and r_2 values are $0.5 \mu\text{m}$. The corresponding E-field and H-field distributions are shown in Fig. 4(b) and

(c), respectively. The electromagnetic energy distributions are similar to the those of single-layer ESM concentrated on four corners of ESM. Fig. 4(d) shows the transmission spectra of dual-layer ESM with different h value at TE mode. The bandwidth of resonance (ω_0) becomes broader at $3.050 \mu\text{m}$.

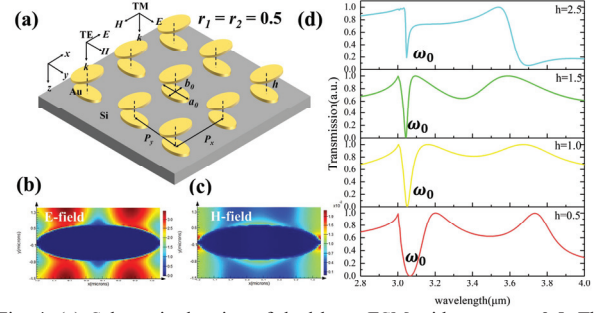


Fig. 4. (a) Schematic drawing of dual-layer ESM with $r_1 = r_2 = 0.5$. The corresponding E-field and H-field contributions are shown in (b) and (c), respectively. (d) The transmission spectra of dual-layer ESM with different h value at TE mode.

IV. CONCLUSION

In conclusion, we present the reconfigurable IR ESMs and study the influences of electromagnetic characteristics by changing the minor-axis and the macro-axis of ESM. The electromagnetic response can be manipulated between single-band and dual-band resonances by changing different ratio of macro-axis and minor-axis of ESM. By varying r value, the electromagnetic behavior of dual-band resonance can be tuned from broad bandwidth to narrow bandwidth, while the corresponding FSR could be controlled from 154 nm to 607 nm depending on the design of symmetrical or asymmetrical ESM. These characteristics can be used to realize filter, optical switch, and environment sensor in IR wavelength range.

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